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APPLICATION NO FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
08 866,129	05 30 1997	TOSHIYA UEMURA	F97-121-USCONT2	9340
75	90 06 10 2003			
McGinn & Gibb PLLC 8321 Old Courthouse Road Suite 200 Vienna, VA 22182-3817			EXAMINER	
			WILLE, DOUGLAS A	
			ART UNIT	PAPER NUMBER

2814 DATE MAILED: 06:10/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.		Applicant(s)				
		08/866,129		UEMURA ET AL				
	Office Action Summary	Examiner		Art Unit				
		Douglas AW		2814				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply								
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1 136(a). In no event, however, may a repty be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U S C § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status								
1)	Responsive to communication(s) filed on 16 J	luly 2002 .						
2a)	This action is FINAL . 2b)∑ Thi	is action is nor	ı-finat.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. Disposition of Claims								
4) Claim(s) 1,2,4-14,20-28 and 30 is/are pending in the application.								
4	4a) Of the above claim(s) is/are withdrawn from consideration.							
5) Claim(s) is/are allowed.								
6) Claim(s) <u>1,2,4-15,20-28 and 30</u> is/are rejected.								
7) Claim(s) is/are objected to.								
8) Claim(s) are subject to restriction and/or election requirement.								
Application Papers								
9) The specification is objected to by the Examiner.								
10) The drawing(s) filed on is/are; a) accepted or b) objected to by the Examiner.								
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1 85(a)								
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner								
If approved, corrected drawings are required in reply to this Office action.								
12) The oath or declaration is objected to by the Examiner.								
Priority under 35 U.S.C. §§ 119 and 120								
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).								
a) All b) Some * c) None of:								
1. Certified copies of the priority documents have been received.								
2. Certified copies of the priority documents have been received in Application No								
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 								
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).								
a) The translation of the foreign language provisional application has been received. 15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.								
Attachment(s)								
2) Notice	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s) <u>34</u>	4) { 5, [6) {		y (PTO-413) Paper No.si Patent Application (PTC-152				
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DETAILED ACTION

Claim Rejections - 35 USC § 102

- 1. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.
- 2. Claims 12 14, 21, 27, 28 and 30 are rejected under 35 U.S.C. 102(e) as being anticipated by Nakamura et al. ('422)
- 3. With respect to claims 12 14, Nakamura et al. ('422) show a group III compound semiconductor device (see Figure 1) with a p-type upper layer 13 and an electrode consisting of a layer of Ni with a layer of Au on top (column 5, line 49). Figure 7 shows a modification of the Figure 1 device which has a contact layer 15 and a bonding pad 17 that covers part of layer 15 and has a protective film of silicon oxide (column 10, line 26). The other properties in claim 12 are inherent in the materials. The limitations of claims 28 and 30 are inherent in the process shown. With respect to claim 27, note that the composition of the atmosphere is a processing limitation and carries no weight in claims drawn to a device
- 4. With respect to claim 21, Nakamura ('422) shows a structure with an AuNi layer covering part of a Ni and Au layer and will inherently have the same properties as claimed.

Claim Rejections - 35 USC § 103

- 5. Claims 1, 2, 4 11, 20 and 22-26 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakamura et al. (*422) in view of Manabe et al. and Nakamura et al. (*350).
- 6. With respect to claims 1 and 22, Nakamura et al. ('422) show a group III compound semiconductor device (see Figure 1) with a p-type upper layer 13 and an electrode consisting of a layer of Ni with a layer of Au on top (column 5, line 49). Figure 7 shows a modification of the

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Figure 1 device which has a contact layer 15 and a bonding pad 17 that covers part of layer 15 and has a protective film of silicon oxide (column 10, line 26). Nakamura et al. ('422) show that the electrode layers are transparent (column 6, line 31). Nakamura et al. ('422) also show that the bonding pad 17 is composed of Ni and Au but teach against the use of Al (in a two layer structure) since it can migrate to the electrode and can degrade it. Manabe et al. show the use of Al in a multilayer electrode stack (see Figure 6 and column 5, line 38) which has improved operating characteristics. It would have been obvious to modify the Nakamura et al. ('422) device to include the Al layer as taught by Manabe et al. with the expectation that the two intervening layers will protect the electrode from deterioration. Nakamura et al. ('422) also teach annealing at 600 degrees (column 7, line 38) and teach the LED compound is InxAlyGa1-x-yN. Nakamura et al. ('350) show that the silicon oxide protective layer is SiO2 (column 34, line 66). Note that no undercutting is shown. The remainder of the claimed features are inherent in the choice of materials. Forming the layers in the sequence Ni-Au-Al follows the decreasing sequence of work functions and would also be obvious.

- 7. With respect to claims 2, 5, and 23, Ni is shown as the first layer.
- 8. With respect to claims 4 and 25, the protective film is silicon oxide.
- 9. With respect to claims 6, 7, 8 and 24, the first layer, Ni has a lower ionization potential and the second layer is Au and relative diffusion is inherent in the structure.
- 10. With respect to claim 9, although it is a processing limitation, it is noted that annealing as 600 degrees is shown.
- 11. With respect to claim 10, AlGalnN is shown.
- 12. With respect to claim 11, a LED is shown.

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13. With respect to claim 20, Nakamura (`422) shows a structure with an AuNi layer covering part of a Ni and Au layer and will inherently have the same properties as claimed

- 14. With respect to claim 22, the adhesiveness is inherent is the structure.
- 15. With respect to claims 26, Ni is shown as the first layer and Al is the third.

Response to Arguments

- 1. Applicant's arguments filed 12/19/01 have been fully considered but they are not persuasive.
- 2. Applicant states that the limitation of annealing in oxygen should be given patentable weight but it has not been shown that the result is a unique structure.
- 3. Applicant states that the references do not show a high resistance layer but the same process will produce the same results.
- 4. Applicant states that the references teache away from the use of Al. However, note that Nakamura et al. ('422) assume that the Al will be use directly on the substrate and express concern for diffusion of Al. Manabe et al. show the use of Al in a multilayer stack that shows improved operation. Thus the intervening layers provide isolation.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Douglas A Wille whose telephone number is (703) 308-4949. The examiner can normally be reached on M-F (6:15-2:45).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (703) 308-4918. The fax phone numbers for the